PLL frequency synthesizer for tuners
BU2614 / BU2614FS

BU2614 PLL frequency synthesizers work up through the FM band. Featuring low radiation noise, low power consumption, and highly sensitive built-in RF amps, they support an IF count function.

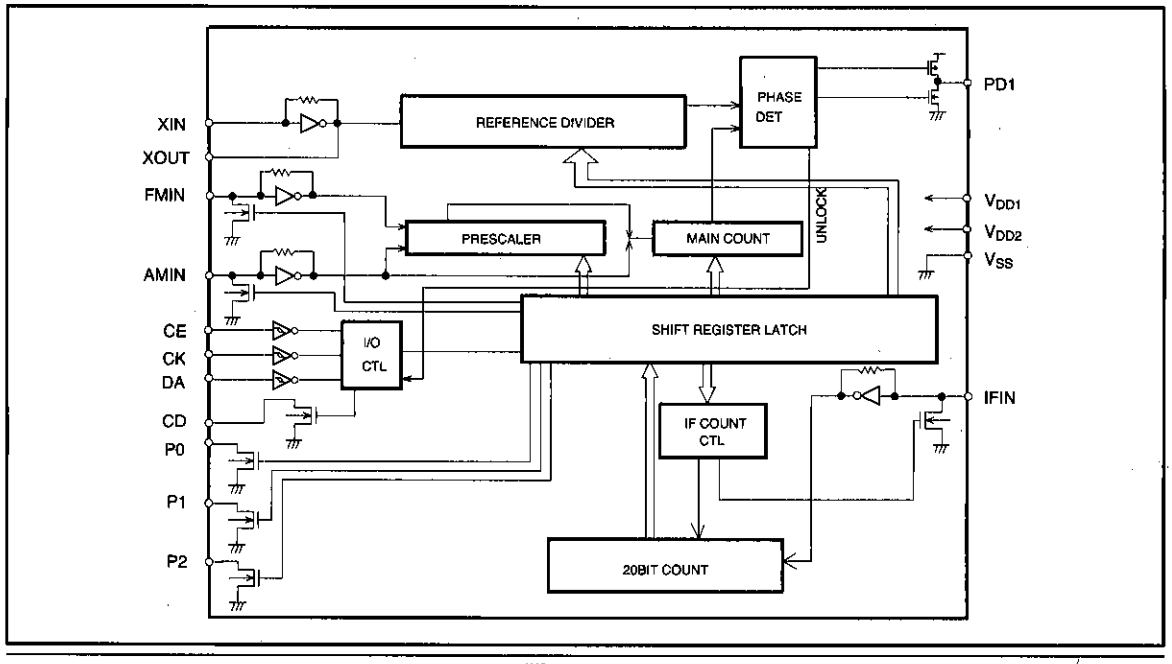
●Applications

Tuners (Mini components, radio cassette players, radio equipment, etc.)

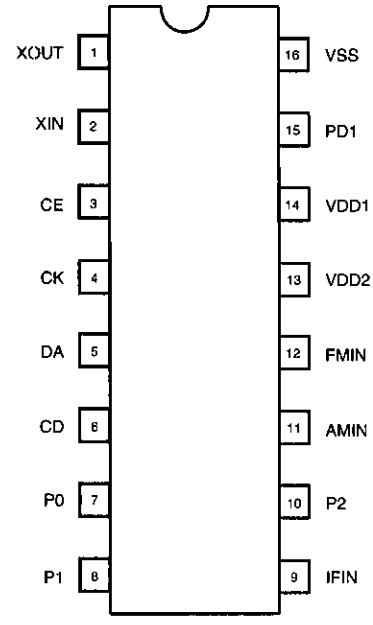
●Features

1) Built-in high-speed prescaler can divide 130MHzVCO.
2) Basic oscillation of 75kHz keeps unnecessary radiation noise to a low level.
3) Low power-consumption (during operation : 4mA PLL OFF 100 μA)
4) In addition to the standard FM and AM, also offers the following 7 frequencies : 25kHz, 12.5kHz, 6.25kHz, 3.125kHz, 5kHz, 3kHz, and 1kHz.
5) Counter for measurement of intermediate frequencies.
6) Unlock detection
7) Three output ports (open drain).
   The BU2615, with seven output ports, is also available.
8) Serial data input (CE.CK.DA)

●Block diagram



●Terminal configuration



●Pin description

Pin No.	Symbol	Terminal name	Function	I/O
1	XOUT	Crystal oscillation terminal	For generation of standard frequency and internal clock.	OUT
2	XIN		Connected to 75 kHz crystal oscillator.	IN
3	CE	Chip enable	When CE is H, DA is synchronous with the rise of CK and read to the internal shift register. DA is then latched at the timing of the fall of CE. Also, output data is output from the CD terminal synchronous to the rise of CK.	IN
4	CK	Serial data		
5	DA	Clock signal		
6	CD	Count data	Frequency data and unlock data are output.	Nch open drain
7	P0	Output port	Controlled on the basis of input data.	
8	P1			
9	IFIN	IF input	Input for frequency measurement.	IN
10	P2	Output port	Controlled on the basis of input data.	Nch open drain
11	AMIN	AM input	Local input for AM	IN
12	FMIN	FM input	Local input for FM	IN
13	V_{DD2}	Power supply 2	4.0V to 6.0V applied for high-speed circuit power supply.	
14	V_{DD1}	Power supply 1	Power supply for logic. 2.7V to 6.0V	
15	PD1	Phase comparison output	High level when value obtained by dividing local output is higher than standard frequency. Low level when value is lower. High impedance when value is same.	3-state
16	V_{SS}	GROUND		

●Absolute maximum ratings (Ta = 25℃)

Parameter		Symbol	Limits	Unit	Conditions
Supply voltage		V_{DD}	−0.3~7.0	V	V_{DD1}, V_{DD2}
Maximum input voltage 1		V_{IN1}	−0.3~7.0	V	CE,CK,DA
Maximum input voltage 2		V_{IN2}	−0.3~V_{DD}0.3	V	XIN,FMIN,AMIN,IFIN
Maximum output voltage 1		V_{OUT1}	−0.3~10.0	V	P_0, P_1, P_2, CD
Maximum output voltage 2		V_{OUT2}	−0.3~V_{DD}0.3	V	PD_1, XOUT
Maximum output current		I_{OUT}	0~3.0	mA	P_0, P_1, P_2, CD
Power dissipation	BU2614	P_D	1000*1	mW	
	BU2614F/FS		500*2		
Operating temperature		Topr	−10~75	℃	
Storage temperature		Tstg	−55~125	℃	

*1 Reduced by 10mW for each increase in Ta of 1°C over 25°C.

*2 Reduced by 5mW for each increase in Ta of 1°C over 25°C.

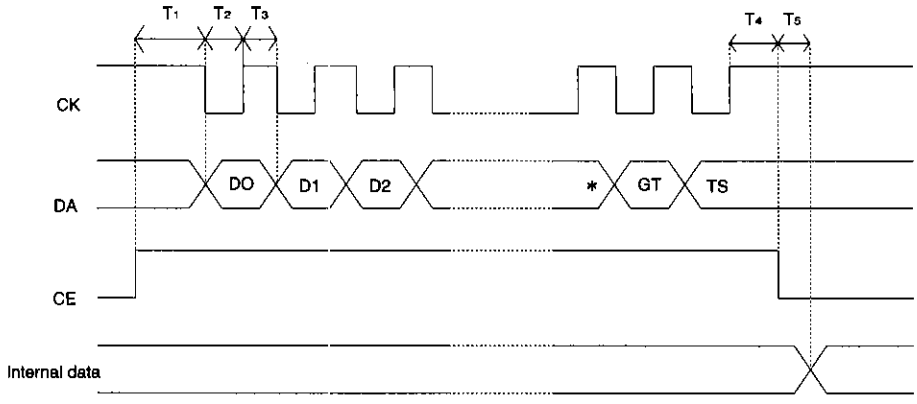
●Recommended operating conditions (Ta = 25℃)

Parameter	Symbol	Limits	Unit
Supply voltage	V_{DD1}	2.7~6.0	V
	V_{DD2}	4.0~6.0	V

●Electrical characteristics (unless other specified, Ta = 25℃, $V_{DD}1$ = $V_{DD}2$ = 5.0V)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Supply current 1	I_{DD1}	—	5.0	10.0	mA	FM_{IN}=130MHz, 100mVrms 13-pin current
Supply current 2	I_{DD2}	—	100	150	μA	14-pin current
Quiescent circuit current	I_{DD3}	—	150	300	μA	No input,, PLL=OFF 13-pin current
"H" level input voltage	V_{IH}	4.0	—	—	V	CE, CK, DA terminals
"L" level input voltage	V_{IL}	—	—	1.0	V	CE, CK, DA terminals
"H" level input current 1	I_{IH1}	—	—	1.0	μA	CE, CK, DA terminals V_{IN}=V_{DD}
"H" level input current 2	I_{IH2}	—	0.3	—	μA	XIN terminal V_{IN}=V_{DD}
"H" level input current 3	I_{IH3}	—	6.0	—	μA	FMIN, AMIN, IFIN terminals V_{IN}=V_{DD}
"L" level input current 1	I_{IL1}	−1.0	—	—	μA	CE, CK, DA terminals V_{IN}=V_{SS}
"L" level input current 2	I_{IL2}	—	−0.3	—	μA	XIN terminals V_{IN}=V_{SS}
"L" level input current 3	I_{IL3}	—	−6.0	—	μA	FMIN, AMIN, IFIN terminals V_{IN}=V_{SS}
"L" level output voltage 1	V_{OL1}	—	0.2	0.5	V	P_0, P_1, P_2, CD I_O=1.0mA
"OFF" level leak current 1	I_{OFF1}	—	—	1.0	μA	P_0, P_1, P_2, CD V_O=10V
"L" level output voltage 2	V_{OL2}	—	0.1	0.5	V	FMIN, AMIN, IFIN I_{OUT}=0.1mA
"H" level output voltage	V_{OH}	V_{DD}−1.0	V_{DD}−0.3	—	V	PD1 I_{OUT}=−1.0mA
"L" level output voltage	V_{OL}	—	0.2	1.0	V	PD1 I_{OUT}=1.0mA
"OFF" level leak current 2	I_{OFF2}	—	—	100	nA	PD1 V_{OUT}=V_{DD}
"OFF" level leak current 3	I_{OFF3}	−100	—	—	nA	PD1 V_{OUT}=Vss
Internal feedback resistor 1	R_{F1}	—	10	—	MΩ	XIN
Internal feedback resistor 2	R_{F2}	—	500	—	kΩ	FMIN, ANIN, IFIN
Input frequency 1	F_{IN1}	10	75	160	kHz	XIN, sine wave, C coupling
Input frequency 2	F_{IN2}	10	—	130	MHz	FMIN, sine wave, C coupling V_{IN}=50mVrms
Input frequency 3	F_{IN3}	0.4	—	30	MHz	AMIN1, sine wave, C coupling V_{IN}=70mVrms
Input frequency 4	F_{IN4}	0.4	—	16	MHz	IFIN, sine wave, C coupling V_{IN}=70mVrms
Maximum input amplitude	F_{INMAX}	—	—	1.5	Vrms	XIN, FMIN, AMIN, IFIN, sine wave, Ccoupling
Minimum pulse width	TW	—	1.0	—	μs	CK, DA
Input rise time	TR	—	—	500	ns	CE, CK, DA
Input fall time	TF	—	—	500	ns	CE, CK, DA

●Input data format



$T_1 \geqq 15\,\mu SEC$ $T_2, T_3 > 1\,\mu SEC$ $T_4 > 0\,\mu SEC$ $T_5 < 15\,\mu SEC$

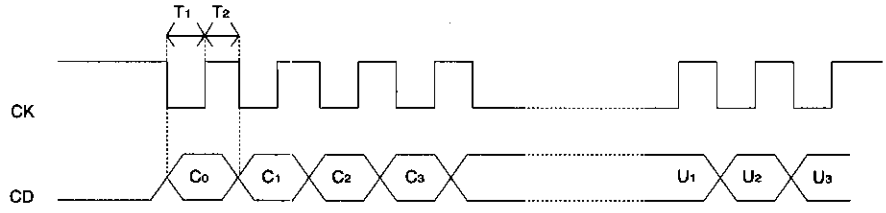
D_0	D_1	D_2	D_3	D_4	D_5	D_6	D_7	D_8	D_9	D_{10}	D_{11}	D_{12}	D_{13}	D_{14}	D_{15}

←Input done from D_0.

P_0	P_1	P_2	*	*	*	*	CT	R_0	R_1	R_2	S	PS	*	GT	TS

* : DON'T CARE

Output data format CE output is LO.



Output data includes pullup resistance. $T_1, T_2 > 1\,\mu SEC$

Output data format

C_0	C_1	C_2	C_3	C_4	C_5	C_6	C_7	C_8	C_9	C_{10}	C_{11}	C_{12}	C_{13}	C_{14}	C_{15}

C_{16}	C_{17}	C_{18}	C_{19}	U_0	U_1	U_2	U_3

←Input done from C_0.

※ Data output only possible when CT = 1 or GT = 1.

●Explanation of the data

(1) Division data : For D_0 through D_{15} (When S = 1, use D_4 through D_{15}.)

D_0	D_1	D_2	D_3	D_4	D_5	D_6	D_7	D_8	D_9	D_{10}	D_{11}	D_{12}	D_{13}	D_{14}	D_{15}

Examples:

Divided frequency =1100(D)=1100÷2=550(D)=226(H) S=0、PS=0 Divided value is double the set value.

0	1	1	0	0	1	0	0	0	1	0	0	0	0	0	0
Divided frequency =1107 (D)=453 (H)				S=1, PS=1											
1	1	0	0	1	0	1	0	0	0	1	0	0	0	0	0
Divided frequency =926 (D)=39E (H)				S=1, PS=0											
×	×	×	×	0	1	1	1	1	0	0	1	1	1	0	0

(2) CT : Frequency measurement beginning data
1 : Beginning of measurement
0 : Internal counter is reset, IFIN is pulldown.

(3) Output port control data : P_0, P_1, P_2
1 : Open drain output ON
2 : Open drain output OFF

(4) R_0, R_1, R_2, standard frequency data

Data			
R0	R1	R2	Standard frequency
0	0	0	25kHz
0	0	1	12.5kHz
0	1	0	6.25kHz
0	1	1	5kHz
1	0	0	3.125kHz
1	0	1	3kHz
1	1	0	1kHz
1	1	1	※PLL OFF

* FMIN = pulldown, AMIN = pulldown, PD = high impedance

(5) S : switch between FMIN and AMIN 0 : FMIN 1 : AMIN

(6) PS : If this bit is set to ON while AMIN is selected, swallow counter division is possible.

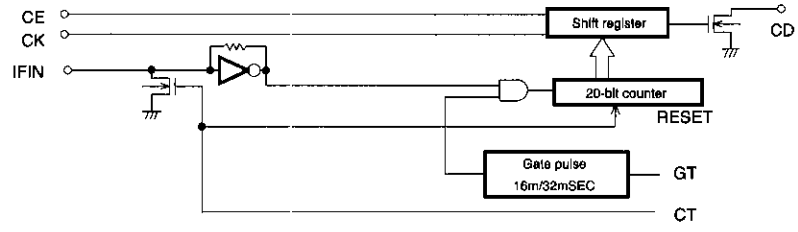
(7) GT : Frequency measurement time and unlock detection ON/OFF

CT	GT	Frequency measurement	Unlock detection	Data output
0	0	OFF	OFF	NG
0	1	OFF	ON	OK
1	0	ON gate time 16 mSEC	ON	
1	1	ON gate time 32 mSEC	ON	

(8) TS : Test data (0) is input.

●Frequency counter

1) Structure



2) How the frequency counter operates

When control data CT equals 1, the 20-bit counter and the amp go into operation. When CT equals 0, input pulldown and the counter are reset. Measuring time (gate pulse) is selected (16mSEC / 32mSEC) on the basis of control data GT. When control data CT equals 0, the counter is reset.

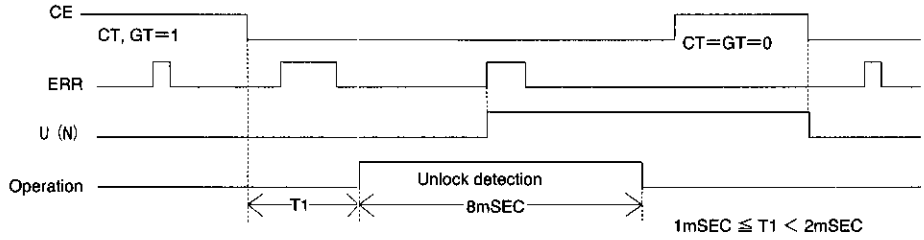
3) Explanation of output data

D_0 : LSB D_{19} : MSB

How the unlock detection circuit operates

When control data GT equals 1, or CT equals 1, the unlock detection circuit goes into operation for 8mSEC. When CT equals 1, the unlock detection circuits stops operating before the frequency counter gate pulse is emitted.

When CT equals 0, or GT equals 0, the unlock detection circuit is reset.

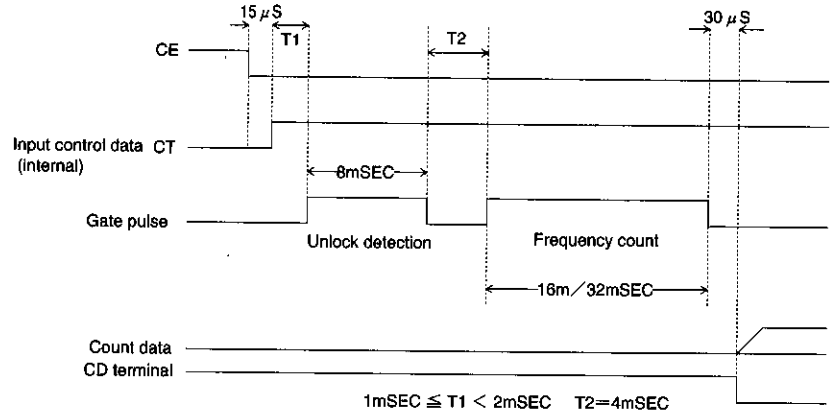


Explanation of output data

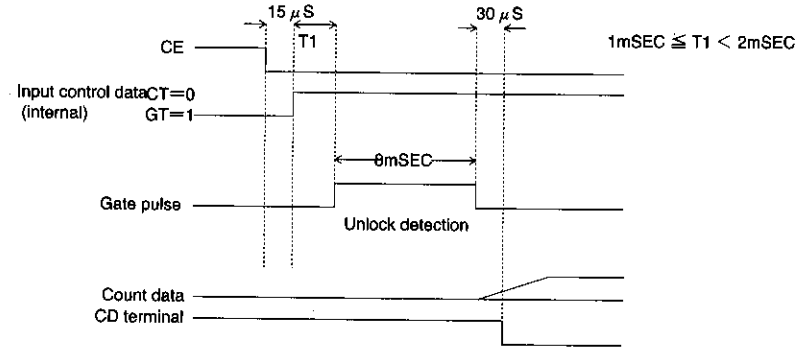
U0	U1	U2	U3	
0	0	0	0	ERR < 7 μSEC
1	0	0	0	7 μSEC < ERR < 13 μSEC
1	1	0	0	13 μSEC < ERR < 26 μSEC
1	1	1	0	26 μSEC < ERR < 54 μSEC
1	1	1	1	54 μSEC < ERR

●How the frequency counter and unlock detection circuit operate

1) When CT = 1 : Frequency count and unlock detection are carried out.

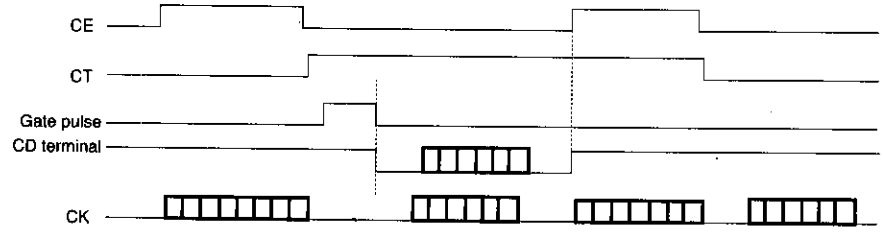


2) When CT = 0 and GT = 1 : Only unlock detection is carried out.



Explanation of CD terminal

When frequency measurement or unlock detection is finished, the CD terminal goes to LO to indicate that the count and unlock detection have finished. It also synchronizes with CK to output counter data. When the next data is input, it goes to HI.



●External dimensions (Unit: mm)

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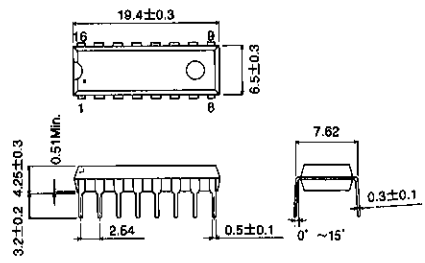

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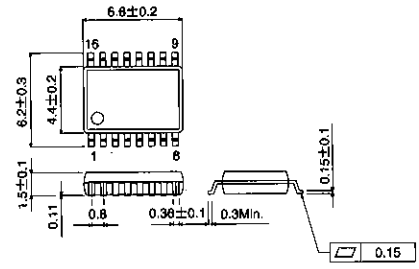

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